BUK9K29-100E

Dual N-channel TrenchMOS logic level FET

28 March 2013 — Product data sheet

1. General description

Dual logic level N-channel MOSFET in a LFPAK56D package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

2. Features and benefits

- Q101 compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True logic level gate with $V_{GS(th)}$ > 0.5 V @ 175 °C

3. Applications

- 12 V Automotive systems
- Motors, lamps and solenoid control
- Start-stop micro-hybrid applications
- Transmission control
- Ultra high performance power switching

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{DS}	drain-source voltage	T_j ≥ 25 °C; T_j ≤ 175 °C		-	-	100	V
I_D	drain current	V_{GS} = 5 V; T_{mb} = 25 °C; Fig. 1		-	-	30	A
P_{tot}	total power dissipation	T_{mb} = 25 °C; Fig. 2		-	-	68	W
T_j	junction temperature			-55	-	175	°C
Static characteristics FET1 and FET2							
R_{DSon}	drain-source on-state resistance	V_{GS} = 5 V; I_D = 5 A; T_j = 25 °C; Fig. 12		-	25.1	29	mΩ
Dynamic characteristics FET1 and FET2							
$Q_{G(tot)}$	total gate charge	I_D = 10 A; V_{DS} = 80 V; V_{GS} = 10 V; T_j = 25 °C; Fig. 14; Fig. 15		-	54	-	nC
Q_{GD}	gate-drain charge			-	10.9	-	nC

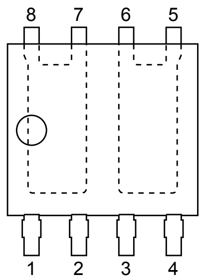
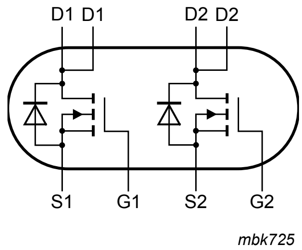
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Avalanche Ruggedness FET1 and FET2							
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	I_D = 30 A; V_{sup} ≤ 100 V; V_{GS} = 5 V; $T_{j(init)}$ = 25 °C; Fig. 3	[1][2]	-	-	83	mJ

[1] Refer to application note AN10273 for further information

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source1	 LFPAK56D (SOT1205)	
2	G1	gate1		
3	S2	source2		
4	G2	gate2		
5	D2	drain2		
6	D2	drain2		
7	D1	drain1		
8	D1	drain1		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BUK9K29-100E	LFPAK56D	Plastic single ended surface mounted package (LFPAK56D); 8 leads	SOT1205

7. Marking

Table 4. Marking codes

Type number	Marking code
BUK9K29-100E	9291E

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25$ °C; $T_j \leq 175$ °C		-	100	V
V_{DGR}	drain-gate voltage	$R_{GS} = 20$ kΩ; $T_j \geq 25$ °C; $T_j \leq 175$ °C		-	100	V
V_{GS}	gate-source voltage	$T_j \leq 175$ °C; DC		-10	10	V
		$T_j \leq 175$ °C; Pulsed	[1][2]	-15	15	V
I_D	drain current	$T_{mb} = 25$ °C; $V_{GS} = 5$ V; Fig. 1		-	30	A
		$T_{mb} = 100$ °C; $V_{GS} = 5$ V; Fig. 1		-	21	A
I_{DM}	peak drain current	$T_{mb} = 25$ °C; pulsed; $t_p \leq 10$ µs; Fig. 4		-	118	A
P_{tot}	total power dissipation	$T_{mb} = 25$ °C; Fig. 2		-	68	W
T_{stg}	storage temperature			-55	175	°C
T_j	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
Source-drain diode FET1 and FET2						
I_S	source current	$T_{mb} = 25$ °C		-	30	A
I_{SM}	peak source current	pulsed; $t_p \leq 10$ µs; $T_{mb} = 25$ °C		-	118	A
Avalanche Ruggedness FET1 and FET2						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 30$ A; $V_{sup} \leq 100$ V; $V_{GS} = 5$ V; $T_{j(init)} = 25$ °C; Fig. 3	[3][4]	-	83	mJ

[1] Accumulated Pulse duration up to 50 hours delivers zero defect ppm
[2] Significantly longer life times are achieved by lowering T_j and or V_{GS}.
[3] Refer to application note AN10273 for further information
[4] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C

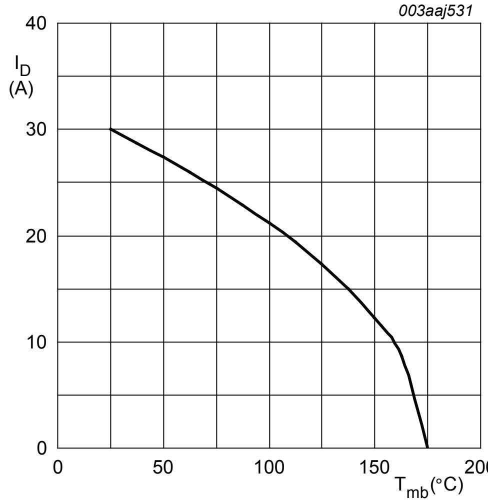


Fig. 1. Continuous drain current as a function of mounting base temperature

$V_{GS} \geq 5V$

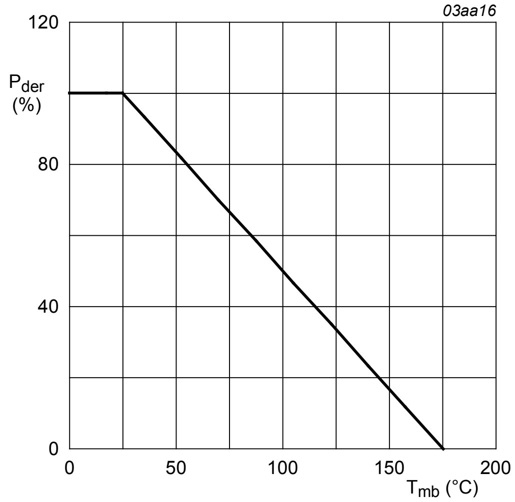


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25°C)}} \times 100\,\%$$

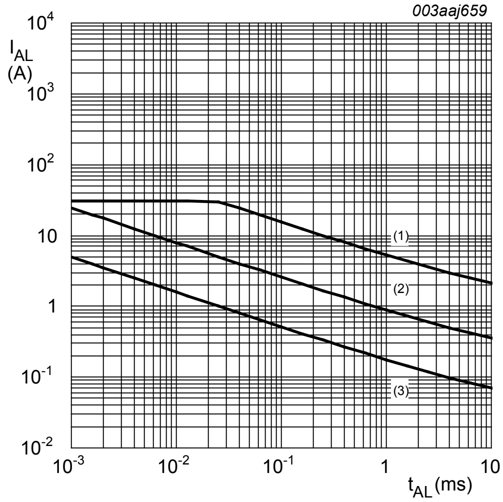


Fig. 3. Single-pulse and repetitive avalanche rating; avalanche current as a function of avalanche time, FET1 and FET2

(1) Single-pulse; $T_j = 25\,°C$.
(2) Single-pulse; $T_j = 150\,°C$.
(3) Repetitive.

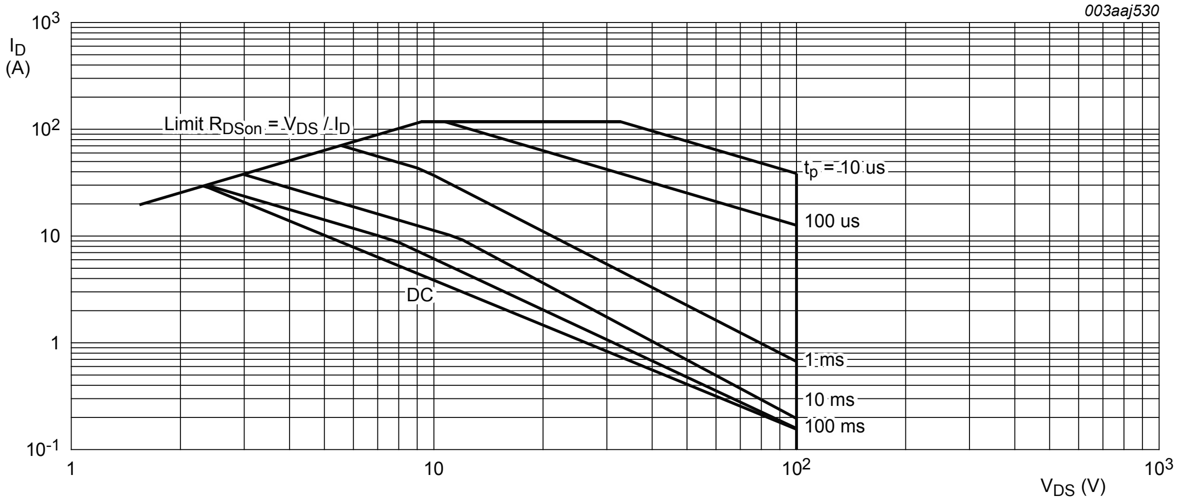


Fig. 4. Safe operating area; continuous and peak drain current as a function of drain-source voltage

$T_{mb} = 25\,°C$; I_{DM} is single pulse

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5		-	-	2.21	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	Minimum footprint; mounted on a printed circuit board		-	95	-	K/W

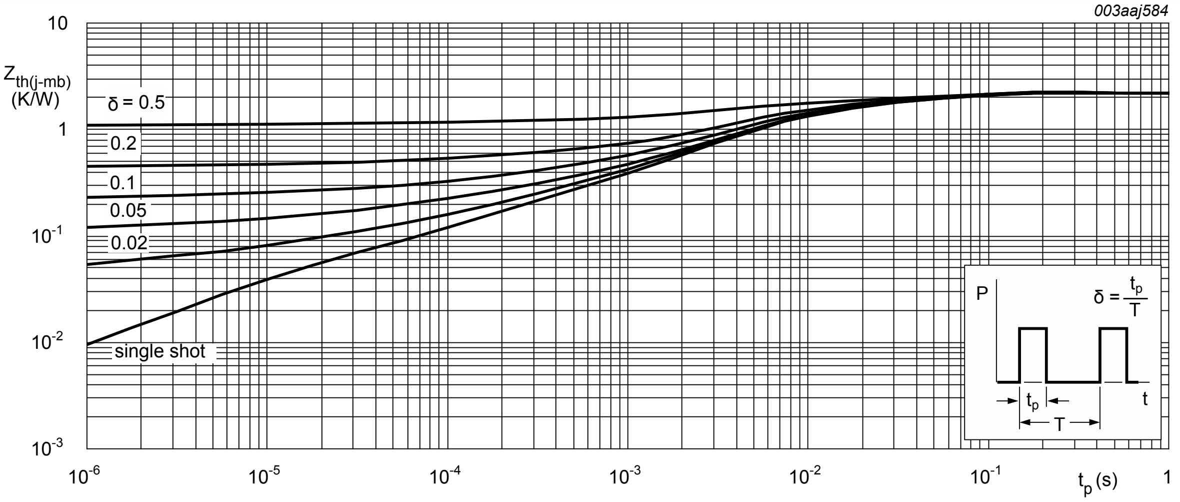


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics FET1 and FET2							
$V_{(BR)DSS}$	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C		90	-	-	V
		I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C		100	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25 °C; Fig. 10; Fig. 11		1.4	1.7	2.1	V
		I_D = 1 mA; V_{DS} = V_{GS}; T_j = 175 °C; Fig. 10; Fig. 11		0.5	-	-	V
		I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55 °C; Fig. 10; Fig. 11		-	-	2.45	V
I_{DSS}	drain leakage current	V_{DS} = 100 V; V_{GS} = 0 V; T_j = 25 °C		-	0.02	1	µA
		V_{DS} = 100 V; V_{GS} = 0 V; T_j = 175 °C		-	-	500	µA
I_{GSS}	gate leakage current	V_{GS} = -10 V; V_{DS} = 0 V; T_j = 25 °C		-	2	100	nA
		V_{GS} = 10 V; V_{DS} = 0 V; T_j = 25 °C		-	2	100	nA
R_{DSon}	drain-source on-state resistance	V_{GS} = 5 V; I_D = 5 A; T_j = 25 °C; Fig. 12		-	25.1	29	mΩ
		V_{GS} = 5 V; I_D = 5 A; T_j = 175 °C; Fig. 12; Fig. 13		-	68.02	80	mΩ
		V_{GS} = 10 V; I_D = 5 A; T_j = 25 °C; Fig. 12		-	22.7	27	mΩ
Dynamic characteristics FET1 and FET2							
$Q_{G(tot)}$	total gate charge	I_D = 10 A; V_{DS} = 80 V; V_{GS} = 10 V; T_j = 25 °C; Fig. 14; Fig. 15		-	54	-	nC
Q_{GS}	gate-source charge	I_D = 10 A; V_{DS} = 80 V; V_{GS} = 10 V; T_j = 25 °C; Fig. 15; Fig. 14		-	5.6	-	nC
Q_{GD}	gate-drain charge	I_D = 10 A; V_{DS} = 80 V; V_{GS} = 10 V; T_j = 25 °C; Fig. 14; Fig. 15		-	10.9	-	nC
C_{iss}	input capacitance	V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz; T_j = 25 °C; Fig. 16		-	2727	3637	pF
C_{oss}	output capacitance			-	169	203	pF
C_{rss}	reverse transfer capacitance			-	106	145	pF
$t_{d(on)}$	turn-on delay time	V_{DS} = 80 V; R_L = 8 Ω; V_{GS} = 10 V; $R_{G(ext)}$ = 5 Ω; T_j = 25 °C; I_D = 10 A		-	6.1	-	ns
t_r	rise time			-	6.4	-	ns
$t_{d(off)}$	turn-off delay time			-	67.3	-	ns
t_f	fall time			-	35.1	-	ns
Source-drain diode FET1 and FET2							
V_{SD}	source-drain voltage	I_S = 15 A; V_{GS} = 0 V; T_j = 25 °C; Fig. 17		-	0.78	1.2	V

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
t_{rr}	reverse recovery time	I_S = 10 A; dI_S/dt = -100 A/µs; V_{GS} = 0 V; V_{DS} = 50 V; T_j = 25 °C		-	32.7	-	ns
Q_r	recovered charge			-	50.1	-	nC

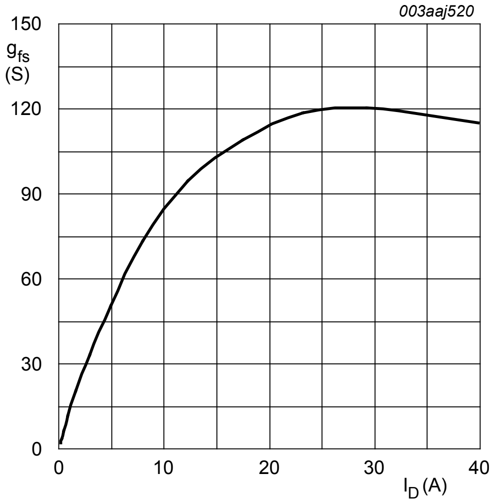


Fig. 6. Forward transconductance as a function of drain current; typical values

$T_j = 25\,°C; V_{DS} = 15\,V$

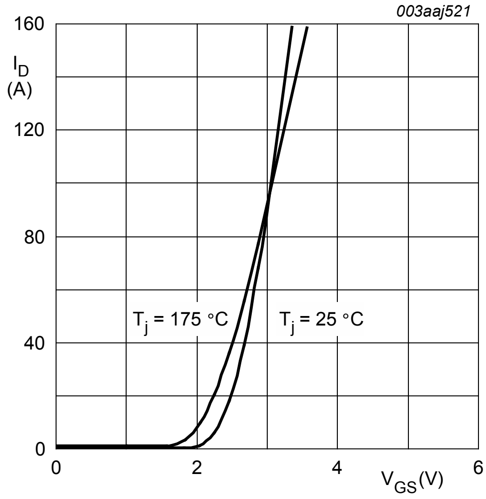


Fig. 7. Transfer characteristics: drain current as a function of gate-source voltage; typical values

$V_{DS} = 10V$

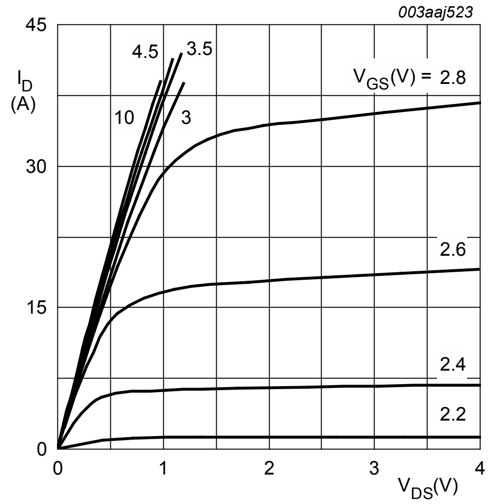


Fig. 8. Output characteristics: drain current as a function of drain-source voltage; typical values

$T_j = 25\,°C$

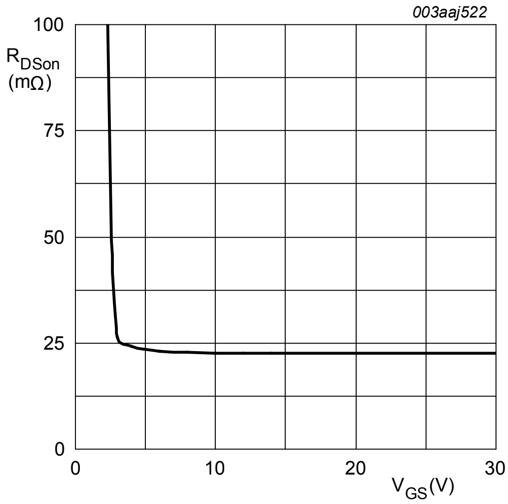


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25\,°C;\ I_D = 5\,A$

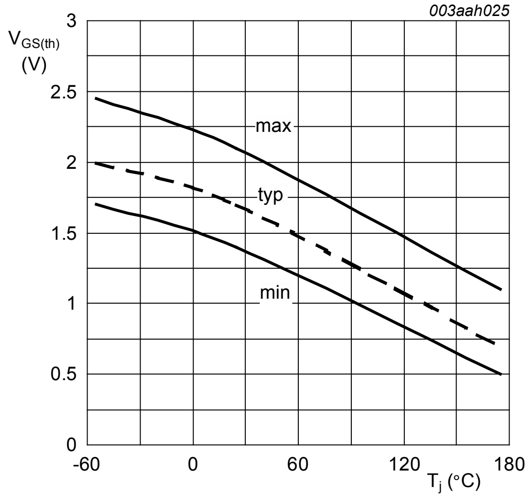


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$I_D = 1$ mA; $V_{DS} = V_{GS}$

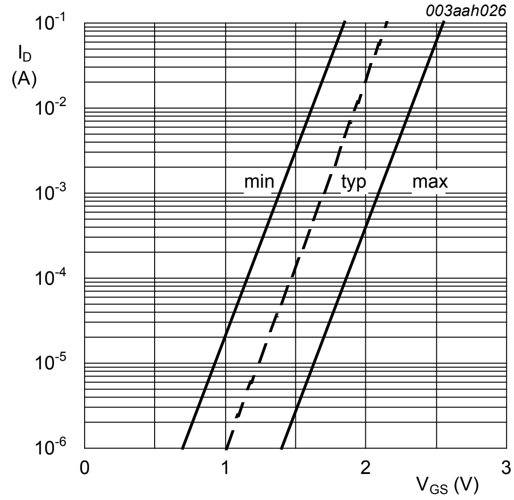


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25°C$; $V_{DS} = 5V$

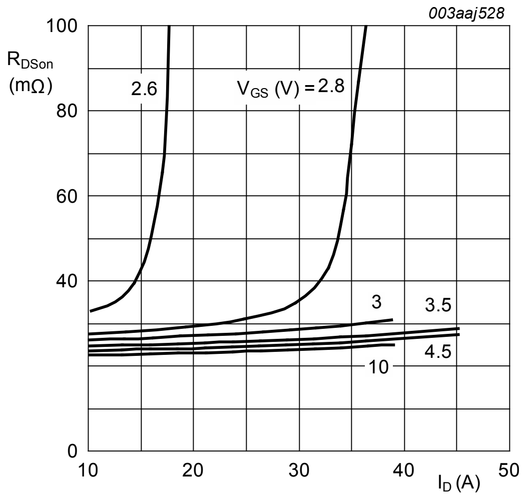


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$T_j = 25\,°C$

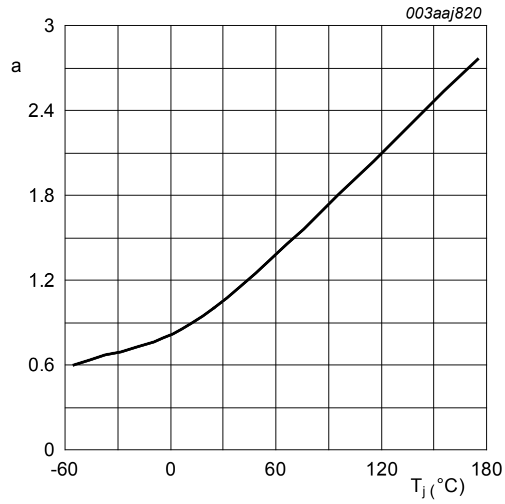


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon\,(25°C)}}$$

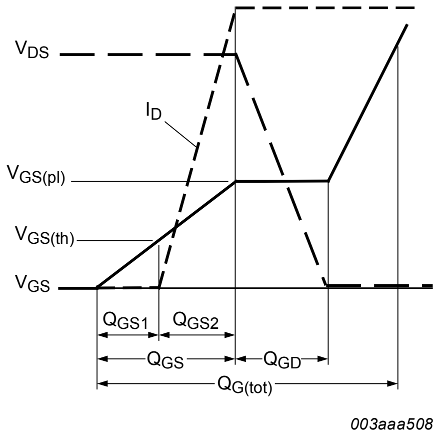


Fig. 14. Gate charge waveform definitions

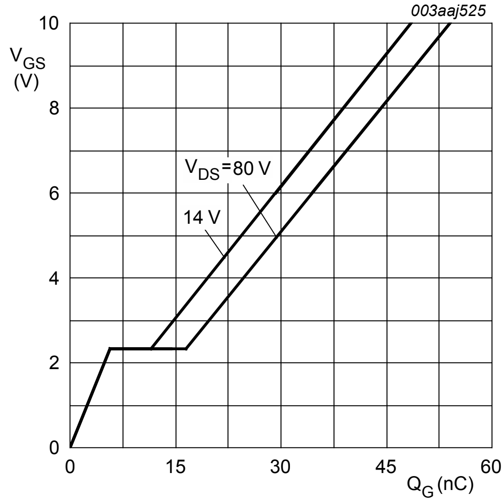


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$T_j = 25\,°C; I_D = 10\,A$

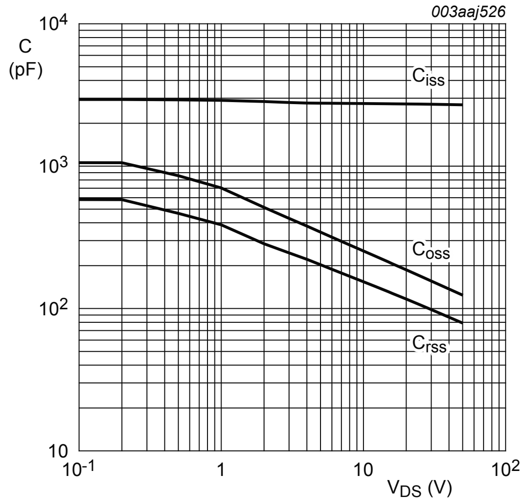


Fig. 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$V_{GS} = 0\,V; f = 1\,MHz$

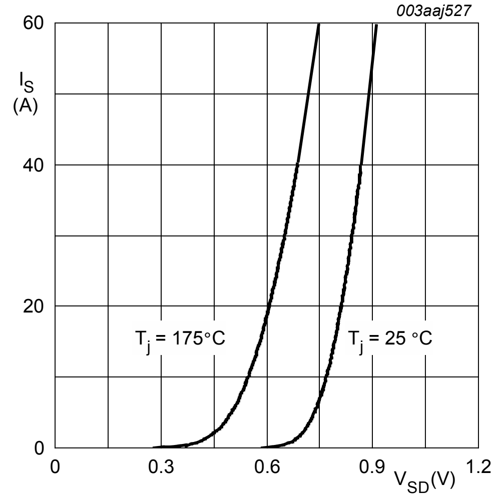
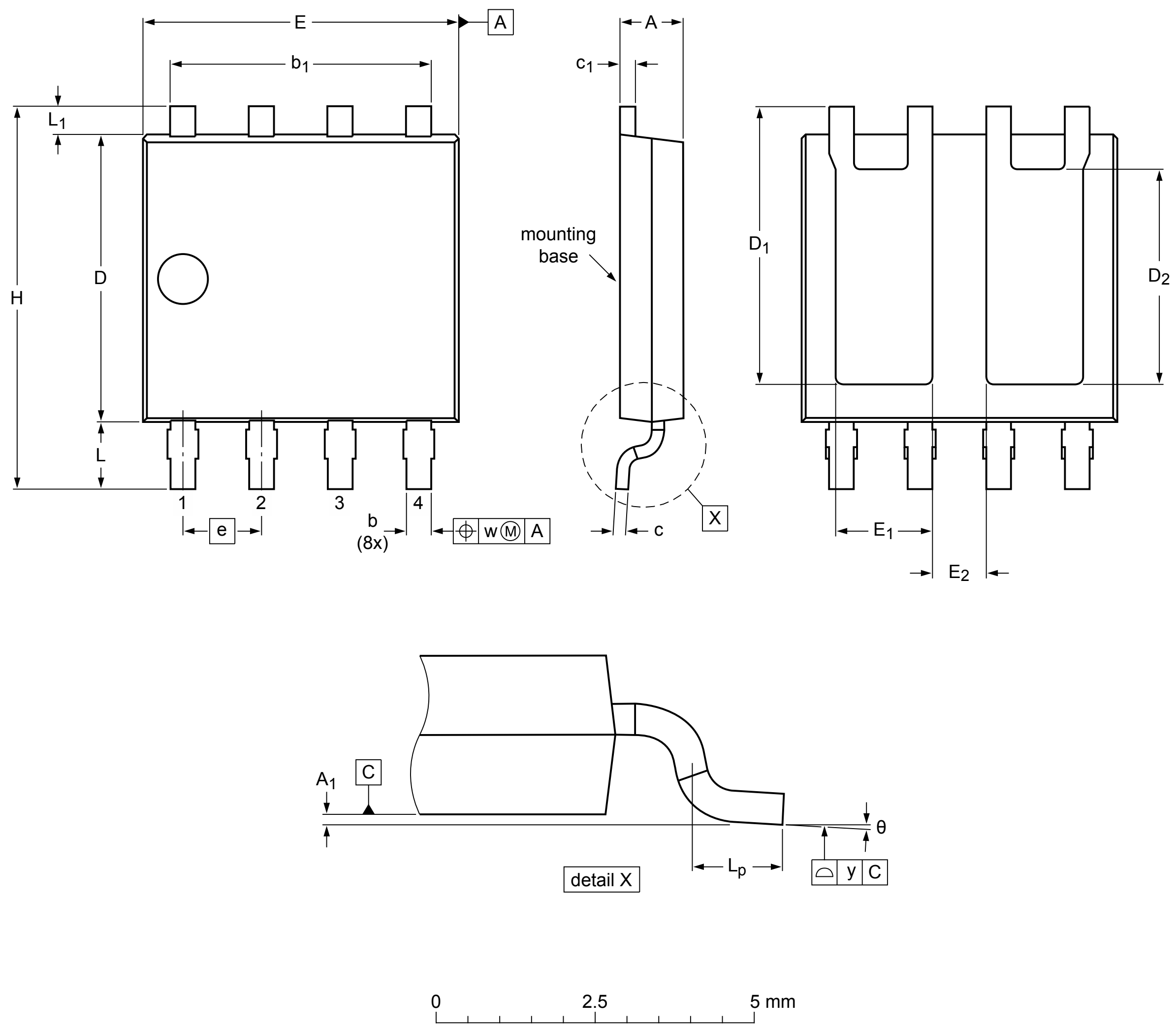


Fig. 17. Source current as a function of source-drain voltage; typical values

$V_{GS} = 0\,V$

11. Package outline

Plastic single ended surface mounted package (LFPAK56D); 8 leads **SOT1205**



Dimensions

Unit		A	A_1	b	b_1	c	c_1	$D^{(1)}$	$D_1^{(1)}$	D_2 (ref)	$E^{(1)}$	$E_1^{(1)}$	E_2	e	H	L	L_1	L_p	w	y	θ
mm	max	1.05	0.1	0.50	4.4	0.25	0.30	4.70	4.8		5.30	1.8	0.85		6.2	1.3	0.55	0.85			8°
	nom									3.5				1.27					0.25	0.1	
	min		0.0	0.35	4.1	0.19	0.24	4.45			4.95	1.6			5.9	0.8	0.30	0.40			0°

Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

sot1205_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1205						~~13-02-19~~ 13-02-21

Fig. 18. Package outline LFPAK56D (SOT1205)

12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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13. Contents

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Date of release: 28 March 2013